Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-150-1014

Inclosure Material:

Metal

Overall Length:

1.253 inches

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-4

Electrode Internally-electrically Connected To Case:

Cathode

Mounting Method:

Threaded stud

Overall Width Across Flats:

Between 0.424 inches and 0.437 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

36.0 repetitive peak reverse voltage, peak total value and 30.0 working peak reverse voltage

Current Rating Per Characteristic:

30.00 amperes forward current, average and 600.00 amperes forward current, average preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 1 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

```
--
```

Demilitarization:

No

Fiig:

A110a0